Diode Semiconductor Device - Page 1 of 1



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Mounting Facility Quantity:	
1	
Mounting Method:	
Terminal and unthreaded hole	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
600.0 reverse voltage, peak and 600.0 working peak reverse voltage,	peak total value
Current Rating Per Characteristic:	
15.00 amperes forward current, dc and 30.00 amperes forward current	, peak total value and 200.00 amperes peak forward surge current
Power Rating Per Characteristic:	
100.0 watts total device dissipation	
Maximum Operating Tempurature Per Measurement Point:	
-65.0 degrees celsius ambient air and 175.0 degrees celsius ambient air	
Terminal Type And Quantity:	
2 pin	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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